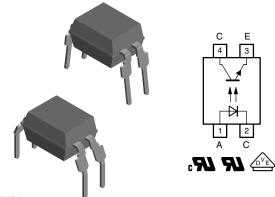
TCET111., TCET111.G

Vishay Semiconductors

Optocoupler, Phototransistor Output, High Temperature, 110 °C, Rated



www.vishay.com

17197_4

LINKS TO ADDITIONAL RESOURCES



DESCRIPTION

The TCET111., TCET111.G consists of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 4 pin plastic dual inline package.

APPLICATIONS

Circuits for safe protective separation against electrical shock according to safety class II (reinforced isolation):

- for appl. class I to IV at mains voltage \leq 300 V
- for appl. class I to III at mains voltage ≤ 600 V according to DIN EN 60747-5-5 (VDE 0884), suitable for:
 - Switch-mode power supplies
 - Line receiver
 - Computer peripheral interface
 - Microprocessor system interface

FEATURES

- CTR offered in 9 groups
- Isolation materials according to UL 94 V-0
- Pollution degree 2 (DIN / VDE 0110 / resp. IEC 60664)
- Climatic classification 55 / 100 / 21 (IEC 60068 part 1)
- Special construction: therefore, extra low coupling capacity of typical 0.2 pF, high common mode rejection
- Low temperature coefficient of CTR
- Temperature range -40 °C to +110 °C
- Rated impulse voltage (transient overvoltage) $V_{IOTM} = 6 kV_{peak}$
- Isolation test voltage (partial discharge test voltage) $V_{pd} = 1.6 \text{ kV}$
- Rated isolation voltage (RMS includes DC) $V_{IOWM} = 600 V_{RMS}$
- Rated recurring peak voltage (repetitive) V_{IORM} = 850 V_{peak}
- Creepage current resistance according to VDE 0303/ IEC 60112 comparative tracking index: CTI ≥ 175
- Thickness through insulation ≥ 4 mm
- External creepage distance > 8 mm
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

AGENCY APPROVALS

- <u>UL</u>
- <u>cUL</u>
- <u>DIN EN 60747-5-5 (VDE 0884)</u>
- BSI: EN 62368-1:2014

ORDERING INFORMATION	
T C E T 1 1 # - # PART NUMBER PACKAGE OPTION OPTION	DIP-4
AGENCY CERTIFIED / PACKAGE CTR (%)	
AGENCY CERTIFIED / PACKAGE 10 mA	
UL, cUL, VDE, BSI 100 to 200 160	to 320
DIP-4 TCET1113	-
DIP-4, 400 mil TCET1113G TCET	T1114G

Rev. 2.1, 17-Dec-2020

1 For technical questions, contact: <u>optocoupleranswers@vishay.com</u> Document Number: 83546







www.vishay.com

Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	SYMBOL	SYMBOL VALUE UNIT						
INPUT									
Reverse voltage		V _R	6	V					
Forward current		I _F	60	mA					
Forward surge current	$t_p \le 10 \ \mu s$	I _{FSM}	1.5	А					
OUTPUT									
Collector emitter voltage		V _{CEO}	70	V					
Emitter collector voltage		V _{ECO}	7	V					
Collector current		I _C	50	mA					
Collector peak current	t_p/T = 0.5, $t_p \leq$ 10 ms	I _{CM}	100	mA					
COUPLER									
Isolation test voltage (RMS)	t = 1 s	V _{ISO}	5000	V _{RMS}					
Operating ambient temperature range		T _{amb}	-40 to +110	°C					
Storage temperature range		T _{stg}	-55 to +125	°C					
Soldering temperature ⁽¹⁾	2 mm from case, \leq 10 s	T _{sld}	260	°C					

Notes

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability

⁽¹⁾ Refer to wave profile for soldering conditions for through hole devices (DIP)

THERMAL CHARACTERISTICS			
PARAMETER	SYMBOL	VALUE	UNIT
LED power dissipation	P _{diss}	70	mW
Output power dissipation	P _{diss}	70	mW
Maximum LED junction temperature	T _{jmax.}	125	°C
Maximum output die junction temperature	T _{jmax.}	125	°C
Thermal resistance, junction emitter to board	θ_{EB}	173	°C/W
Thermal resistance, junction emitter to case	θ_{EC}	149	°C/W
Thermal resistance, junction detector to board	θ_{DB}	111	°C/W
Thermal resistance, junction detector to case	θ_{DC}	127	°C/W
Thermal resistance, junction emitter to junction detector	θ_{ED}	173	°C/W
Thermal resistance, board to ambient $^{\left(1\right) }$	θ_{BA}	197	°C/W
Thermal resistance, case to ambient $^{\left(1\right) }$	θ_{CA}	4041	°C/W

Notes

 The thermal model is represented in the thermal network below. Each resistance value given in this model can be used to calculate the temperatures at each node for a given operating condition. The thermal resistance from board to ambient will be dependent on the type of PCB, layout and thickness of copper traces. For a detailed explanation of the thermal model, please reference Vishay's "Thermal Characteristics of Optocouplers" application note

⁽¹⁾ For 2 layer FR4 board (4" x 3" x 0.062")





www.vishay.com

Vishay Semiconductors

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION SYMBOL MIN. TYP. MAX.								
INPUT									
Forward voltage	I _F = 50 mA	V _F	-	1.25	1.6	V			
Junction capacitance	$V_R = 0$, f = 1 MHz	Cj	-	50	-	pF			
OUTPUT	OUTPUT								
Collector emitter voltage	I _C = 1 mA	V _{CEO}	70	-	-	V			
Emitter collector voltage	I _E = 100 μA	V _{ECO}	7	-	-	V			
Collector emitter cut-off current	$V_{CE} = 20 \text{ V}, \text{ I}_{F} = 0 \text{ A}$	I _{CEO}	-	10	100	nA			
COUPLER									
Collector emitter saturation voltage	I _F = 10 mA, I _C = 1 mA	V _{CEsat}	-	-	0.3	V			
Cut-off frequency	$\label{eq:VCE} \begin{array}{l} V_{CE} = 5 \; V, \; I_{F} = 10 \; mA, \\ R_{L} = 100 \; \Omega \end{array}$	f _c	-	110	-	kHz			
Coupling capacitance	f = 1 MHz	C _k	-	0.6	-	pF			

Note

⁽¹⁾ Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

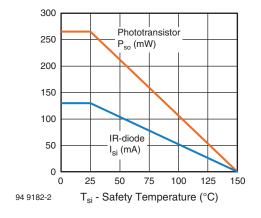
CURRENT TRANSFER RATIO ($T_{amb} = 25 \text{ °C}$, unless otherwise specified)									
PARAMETER	TEST CONDITION PART SYMBOL MIN. TYP. MAX.								
I _C /I _F	V _{CE} = 5 V, I _F = 1 mA	TCET1112G	CTR	22	45	-	%		
		TCET1113, TCET1113G	CTR	34	70	-	%		
		TCET1114G	CTR	56	90	-	%		
	$V_{CE} = 5 \text{ V}, \text{ I}_{F} = 5 \text{ mA}$	TCET1110G	CTR	50	-	600	%		
	V _{CE} = 5 V, I _F = 10 mA	TCET1112G	CTR	63	-	125	%		
		TCET1113, TCET1113G	CTR	100	-	200	%		
		TCET1114G	CTR	160	-	320	%		

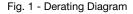
SAFETY AND INSULATION RATED PARAMETERS								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Partial discharge test voltage - routine test	100 %, t _{test} = 1 s	V _{pd}	1.6			kV		
Partial discharge test voltage - lot test (sample test)	t _{Tr} = 60 s, t _{test} = 10 s,	V _{IOTM}	8			kV		
	(see figure 2)	V _{pd}	1.36			kV		
Insulation resistance	V _{IO} = 500 V	R _{IO}	10 ¹²			Ω		
	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 100 ^{\circ}\text{C}$	R _{IO}	10 ¹¹			Ω		
	V _{IO} = 500 V, T _{amb} = 150 °C (construction test only)	R _{IO}	10 ⁹			Ω		
Forward current		I _{si}			130	mA		
Power dissipation		P _{so}			265	mW		
Rated impulse voltage		V _{IOTM}			6	kV		
Safety temperature		T _{si}			150	°C		

Note

According to DIN EN 60747-5-5 (see Fig. 2). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance
with the safety ratings shall be ensured by means of suitable protective circuits.









Vishay Semiconductors

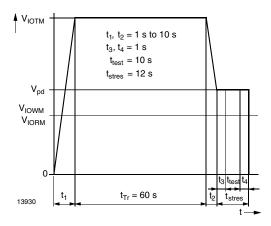


Fig. 2 - Test Pulse Diagram for Sample Test according to DIN EN 60747-5-5 (VDE 0884-5)

SWITCHING CHARACTERISTICS ($T_{amb} = 25 \text{ °C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Delay time	$\label{eq:VS} \begin{array}{l} V_S = 5 \ V, \ I_C = 2 \ mA, \ R_L = 100 \ \Omega, \\ (see \ figure \ 3) \end{array}$	t _d		3		μs	
Rise time	$\label{eq:VS} \begin{array}{l} V_S = 5 \mbox{ V}, \mbox{ I}_C = 2 \mbox{ mA}, \mbox{ R}_L = 100 \ \Omega, \\ (see \mbox{ figure 3}) \end{array}$	t _r		3		μs	
Fall time	$V_{S} = 5 \text{ V}, \text{ I}_{C} = 2 \text{ mA}, \text{ R}_{L} = 100 \Omega,$ (see figure 3)	t _f		4.7		μs	
Storage time	$V_{S} = 5 \text{ V}, \text{ I}_{C} = 2 \text{ mA}, \text{ R}_{L} = 100 \Omega,$ (see figure 3)	t _s		0.3		μs	
Turn-on time	$\label{eq:VS} \begin{array}{l} V_S = 5 \mbox{ V}, \mbox{ I}_C = 2 \mbox{ mA}, \mbox{ R}_L = 100 \ \Omega, \\ \mbox{ (see figure 3)} \end{array}$	t _{on}		6		μs	
Turn-off time	$\label{eq:VS} \begin{array}{l} V_S = 5 \ V, \ I_C = 2 \ mA, \ R_L = 100 \ \Omega, \\ (see \ figure \ 3) \end{array}$	t _{off}		5		μs	
Turn-on time	$\label{eq:VS} \begin{array}{l} V_S = 5 \ V, \ I_F = 10 \ mA, \ R_L = 1 \ k\Omega, \\ (see \ figure \ 4) \end{array}$	t _{on}		9		μs	
Turn-off time	$\label{eq:VS} \begin{array}{l} V_S = 5 \ V, \ I_F = 10 \ mA, \ R_L = 1 \ k\Omega, \\ (see \ figure \ 4) \end{array}$	t _{off}		10		μs	

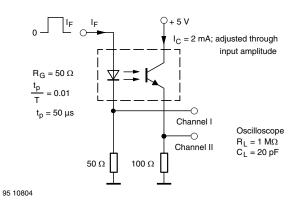


Fig. 3 - Test Circuit, Non-Saturated Operation

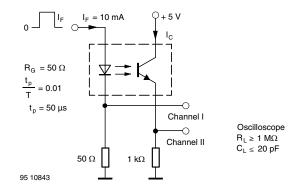


Fig. 4 - Test Circuit, Saturated Operation

Rev. 2.1, 17-Dec-2020

4

Document Number: 83546

For technical questions, contact: <u>optocoupleranswers@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



TCET111., TCET111.G

Vishay Semiconductors

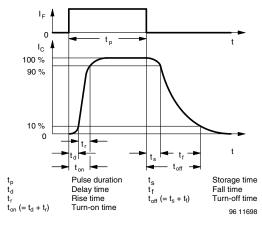


Fig. 5 - Switching Times

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

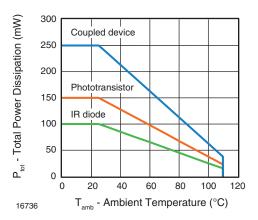


Fig. 6 - Total Power Dissipation vs. Ambient Temperature

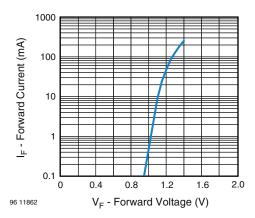
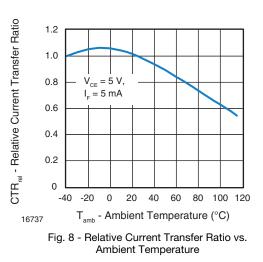


Fig. 7 - Forward Current vs. Forward Voltage



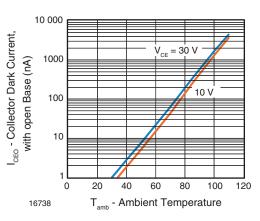


Fig. 9 - Collector Dark Current vs. Ambient Temperature

Rev. 2.1, 17-Dec-2020

5 Justions, contact: optocoupleranswers Document Number: 83546

For technical questions, contact: <u>optocoupleranswers@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Fig. 10 - Collector Current vs. Forward Current

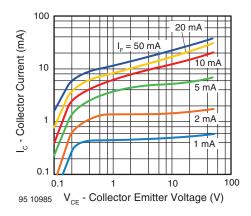


Fig. 11 - Collector Current vs. Collector Emitter Voltage

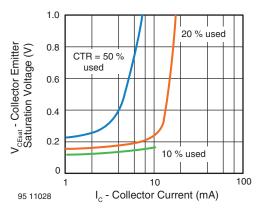


Fig. 12 - Collector Emitter Saturation Voltage vs. Collector Current

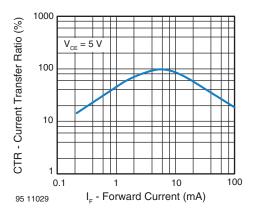


Fig. 13 - Current Transfer Ratio vs. Forward Current

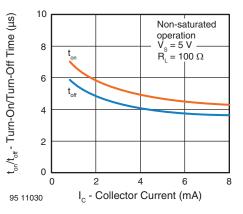


Fig. 14 - Turn-on/off Time vs. Collector Current

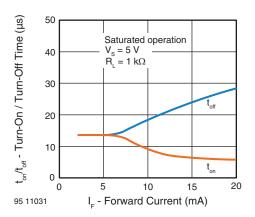


Fig. 15 - Turn-on/off Time vs. Forward Current

TCET111., TCET111.G

Vishay Semiconductors

Rev. 2.1, 17-Dec-2020

6

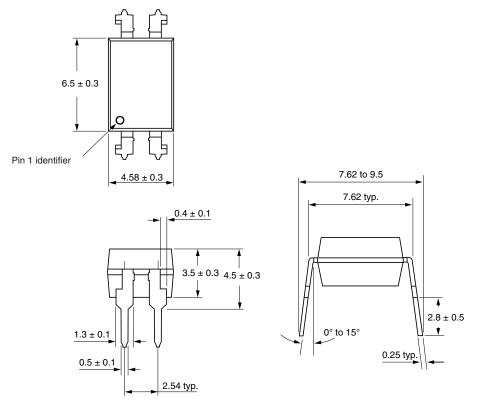
For technical questions, contact: <u>optocoupleranswers@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



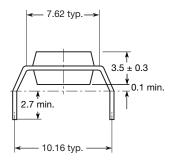
TCET111., TCET111.G

Vishay Semiconductors

PACKAGE DIMENSIONS in millimeters

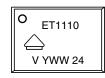


TCET1110G type



i178027-19

PACKAGE MARKING (example)





Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Transistor Output Optocouplers category:

Click to view products by Vishay manufacturer:

Other Similar products are found below :

LTV-814S-TA LTV-824HS LTV-852S 66095-001 6N136-X017T MCT6-X007 MOC8101-X017T PS2561A-1-W-A PS2561B-1-L-A PS2561L-1-V-A MRF658 IL755-1X007 ILD74-X001 ILQ615-2X017 ILQ615-3X016 LDA102S LDA110S PS2561-1-V-W-A PS2561AL-1-V-A PS2561L1-1-L-A PS2701A-1-F3-P-A PS2801-1-F3-P-A PS2911-1-L-AX CNY17-2X017 CNY17-4X001 CNY17-4X017 CNY17F-1X007 CNY17F-2X017 CNY17F-4X001 CNY17G-1 LTV-214 LTV-702VB LTV-733S LTV-816S-TA LTV-825S TCET1113 TCET2100 4N25-X007T IL215AT ILD615-1X007 ILQ2-X007 VOS615A-2T WPPC-A11066AA WPPC-A11066AD WPPC-A11084ASS WPPC-A21068AA WPPC-D11066AA WPPC-D21068ED WPPC-D410616EA WPPC-D410616ED